Modification of the ground state in Sm-Sr manganites by oxygen isotope substitution

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The effect of ${}^{16}\text{O} \rightarrow {}^{18}\text{O}$ isotope substitution on electrical resistivity and magnetic susceptibility of $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ manganites is analyzed. It is shown that the oxygen isotope substitution drastically affects the phase diagram at the crossover region between the ferromagnetic metal state and that of antiferromagnetic insulator (0.4<*x*<0.6), and induces the metal-insulator transition at for *x*=0.475 and 0.5. The nature of antiferromagnetic insulator phase is discussed.

DOI: 10.1103/PhysRevB.67.100410

PACS number(s): 75.47.Gk, 64.60.Ak, 64.75.+g, 75.30.Kz

Despite intense studies, the nature of the colossal magnetoresistance in manganites is still a matter of hot debate. This phenomenon is usually observed when the system is close to a borderline between ferromagnetic metallic (FM) phase and an insulating (I) one. The type of the latter may be different [paramagnetic or antiferromagnetic (AF)], but there are more and more indications that there exists also some kind of charge ordering (CO)-either real long-range CO (see review article,¹ and references therein) or, at least, short-range CO correlations.^{2,3} When the system is close to a FM-I crossover, even weak perturbations can induce this crossover: change of temperature,⁴ magnetic field,⁵ pressure,⁶ irradiation,⁷ etc. In La-Nd-Ca (Ref. 8) and La-Pr-Ca (Ref. 9) manganites, one can induce this crossover and, consequently, the metal-insulator transition even by changing the oxygen isotope content: whereas the low-temperature state of ¹⁶O samples is FM, the samples ¹⁸O become CO AF insulator. This was confirmed by direct neutron scattering study.¹⁰

The question arises whether this spectacular phenomenon is confined only to this particular situation of insulating phase with the charge ordering and the CE-type magnetic structure, i.e., whether the nature of competing phases, particularly, the insulating one, is crucial, or one can get similar behavior in other systems close to the FM-I crossover. In studying this question, we have found a different system with the metal-insulator transition induced by the oxygen isotope substitution: $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ with x in the 0.475–0.5 range. The neutron scattering results for this system at x = 0.4 (Ref. 11) and x=0.5 (Ref. 12), as well as preliminary data¹³ for x = 0.45 with ¹⁸O suggest that, in contrast to (La,Pr) CaMnO₃, the insulating phase here has the A-type antiferromagnetic structure rather than CE. Thus, we could conclude that the metal-insulator transition induced by the isotope substitution is a general property of a FM-I crossover, independent of the detailed nature of the insulating phase. Let us also

note here that x-ray, neutron, and electron diffraction demonstrated possible existence of a short-range charge ordering for $\text{Sm}_{1-\chi}\text{Sr}_{\chi}\text{MnO}_3$ in the concentration range under discussion.¹⁴ The results of ESR¹⁵ and Raman¹⁶ measurements lead to the same conclusion.

Ceramic Sm_{1-x}Sr_xMnO₃ samples were prepared by the solid-state reaction technique, the detailed procedure is described in Ref. 17. The enrichment of the samples by ¹⁸O was performed at T=950 °C and at pressure p=1 bar for 200 h using the method reported in Refs. 9,18. The resistivity of the samples was measured by the conventional four-probe technique in the temperature range from 4.2 to 300 K. The measurements of ac magnetic susceptibility $\chi(T)$ were performed in ac magnetic field with frequency 667 Hz and amplitude of about 0.4 Oe.

The temperature dependence of electrical resistivity $\rho(T)$ for Sm_{1-x}Sr_xMnO₃ samples with x = 0.425, 0.450, 0.475, 0.500, and 0.525 annealed both in ¹⁶O and ¹⁸O atmosphere, is presented in Fig. 1. Four ¹⁶O-containing samples, with x = 0.425, 0.450, 0.475, and 0.500, are characterized by a metallike behavior at low temperatures, Fig. 1(a). With the growth of *x*, the resistivity increases and the metal-insulator transition point T_{MI} shifts toward lower temperatures [T_{MI} was determined as a point corresponding to the maximum temperature derivative of $\rho(T)$ below the resistivity peak]. This can be attributed to the narrowing of the electron bandwidth and the weakening of ferromagnetic interaction probably related to the formation of an inhomogeneous state with ferromagnetic clusters. The sample with x = 0.525 is an insulator down to the lowest temperatures.

After the ${}^{16}\text{O} \rightarrow {}^{18}\text{O}$ isotope substitution, only two samples with the lowest Sr content (x = 0.425 and 0.450) remain metallike at low temperatures, the other become insulating, see Fig. 1(b). These metallic samples have much higher resistivity than those with ${}^{16}\text{O}$. T_{MI} decreases by 40



FIG. 1. Temperature dependence of electrical resistivity for $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ with x = 0.425 (1), 0.450 (2), 0.475 (3), 0.500 (4), and 0.525 (5). The results for samples with ¹⁶O and ¹⁸O are presented at panels (a) and (b), respectively. The inset in panel (a) illustrates the metal-insulator transition induced by the oxygen isotope substitution for samples with x = 0.500. The inset in panel (b) shows the evolution of resistivity with increasing magnetic field for the ¹⁸O sample with x = 0.500. Solid and dashed lines correspond to cooling and heating, respectively.

K and 60 K for the samples with x = 0.425 and 0.450, respectively. For x = 0.475 and 0.500, we observed the metalinsulator transition induced by the oxygen isotope substitution [see inset in Fig. 1(a)], similar to that reported for La-Pr manganites.⁹ Thus, in this system, the ${}^{16}O \rightarrow {}^{18}O$ isotope substitution leads to the changes in the phase diagram: the weakening of the ferromagnetism and the stabilization of the insulating phase (antiferromagnetic, probably with a shortrange CO). A more pronounced thermal hysteresis in $\rho(T)$ curves for the ${}^{18}O$ samples is a manifestation of their enhanced inhomogeneity. A relatively low magnetic field (H= 1 T) transforms the samples with ${}^{18}O$ to the metallike state and suppresses the contribution from the highresistivity insulating state [for x = 0.500, see inset in Fig. 1(b)].

The temperature dependence of the real part of ac magnetic susceptibility $\chi'(T)$ for Sm_{1-x}Sr_xMnO₃ system is presented in Fig. 2. The steep growth of $\chi'(T)$ corresponds to the onset of FM ordering; the Curie temperature T_C was determined as a point corresponding to the maximum $d\chi'(T)/dT$. For samples with ¹⁶O and x = 0.425, 0.450, and 0.475, $\chi'(T)$ behaves in a similar manner (as far as the magnitude of χ' and T_C are concerned). One sees that these



FIG. 2. Temperature dependence of ac magnetic susceptibility for $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ with x=0.425 (1), 0.450 (2), 0.475 (3), 0.500 (4), and 0.525 (5). The behavior of the inverse susceptibility is illustrated in the insets. The results for samples with ¹⁶O and ¹⁸O are presented at panels (a) and (b). Solid and dashed lines correspond to cooling and heating, respectively.

samples are essentially ferromagnetic. The cusp at about 30 K is most probably related to the magnetic ordering in the Sm sublattice. The behavior of χ' at low temperatures (decrease after reaching a maximum) can be connected with the effect of magnetic domains, see Ref. 19, with the other types of magnetic inhomogeneities maybe of the cluster glass type.

For x=0.500, the χ' value drops drastically, T_C shifts toward lower temperatures, this is a signature of the decreasing contribution of the FM phase. For the composition with x=0.525, the susceptibility becomes very small, and the ferromagnetism almost disappears. In the samples with ¹⁸O, for compositions with $x \ge 0.450$, the χ' value is significantly lower in comparison to the samples with ¹⁶O, T_C is also much lower and the hysteresis appears. The FM phase content decreases so steeply that it becomes insufficient for the percolation in the samples with x=0.475 and 0.500, as it is clearly seen for the corresponding $\rho(T)$ curves. The similar manifestations of the two-phase behavior related to the changes in volume fractions of competing ground states were observed for other systems, see, for example, Refs. 20,21.

The temperature dependence of inverse ac magnetic susceptibility $1/\chi'(T)$ for Sm_{1-x}Sr_xMnO₃ manganite samples with ¹⁶O and ¹⁸O is shown in insets in Figs. 2(a) and 2(b), respectively. Above the magnetic ordering temperature, the behavior of $1/\chi'(T)$ curves is rather complicated, suggesting

the existence of an inhomogeneous state even in the paramagnetic region. At relatively high temperatures, $T \sim 250-300$ K, all $1/\chi'(T)$ are very close to each other, exhibiting a nearly linear growth of the Curie-Weiss type. With the temperature lowering, the curves flatten, the flattening being more pronounced for larger x. For x=0.475, x=0.500, we can see even a plateau in $1/\chi'(T)$. The onset temperature for the flattening and deviation of $1/\chi'(T)$ curves for different x seems to be related to the arising of AF correlations accompanied by CO ($T_{CO} \approx 240$ K). This value agrees with the data of Refs. 15 and 22. The behavior of $1/\chi'(T)$ at $T < T_{CO}$ can be interpreted in a picture of interacting and competing FM and AF correlations, the latter growing with x. Similar behavior was reported in Ref. 4.

At $T > T_C$, the ¹⁶O \rightarrow ¹⁸O isotope substitution does not change the general features of $1/\chi'(T)$ curves: the deviations from the Curie-Weiss law begin at the same temperature, below which the slope of $1/\chi'(T)$ is virtually independent of the isotope content at a given value of x. However, for the heavier isotope, T_C becomes lower and $1/\chi'$ increases. Thus, for the samples with ¹⁸O, the plateau in $1/\chi'(T)$ curves is observed within a wider temperature range. We can argue that the AF correlations related to the short-range charge ordering arise in the ¹⁸O samples at the same temperature $T_{CO} \approx 240$ K, but exist down to lower temperatures, i.e., the FM interaction becomes weaker. In the samples with ¹⁸O, the transition to the FM state is characterized by a broader hysteresis in comparison to that for the ¹⁶O samples.

From the data presented above, one sees that the ¹⁶O \rightarrow ¹⁸O isotope substitution induces the metal-insulator transition close to the crossover to an insulating state. According to Ref. 14, for ¹⁶O samples, such a crossover starts already at x=0.4 and extends up to x=0.6. As follows from our data, the actual change of the ground state occurs at $x\sim0.5$ (although an inhomogeneous state with some traces of the FM phase may exist up to x=0.6).

The exact nature of an insulating phase for $x \ge 0.5$ is not yet established with certainty, but the neutron scattering data¹³ show that it is an A-type antiferromagnet. This agrees with the general trend characteristic of $R_{1-r}Sr_rMnO_3$ manganites, where the A-type "bad metal" state was observed for $x \approx 0.5$ in compounds with R = La (Ref. 23) and Nd (Ref. 24), and with the theoretical considerations.^{25,26} In our case, this state is insulating but the resistivity and the energy gap in it at low temperatures are much smaller than in $(La_{1-y}Pr_y)_{0.7}Ca_{0.3}MnO_3$ with y=0.75, for which the isotope-induced metal-insulator transition was first observed in Ref. 9. Indeed, whereas the room temperature resistivities of these two systems are comparable $[0.29 \ \Omega \ cm$ in $(SmSr)MnO_3$ vs 0.37 Ω cm in $(LaPr)CaMnO_3$], the resistivities at 60 K are already much different: $3.5 \times 10^3 \ \Omega \ cm$ for SmSr system vs $2.9 \times 10^7 \ \Omega$ cm for (LaPr)Ca one. Note that the samples of both systems had similar porosity and mean grain size. The effective activation energies at lowest temperatures can be estimated as ~ 15 meV for the SmSr case, but \sim 120 meV for (LaPr)Ca.

The insulating behavior of SmSr samples can be either related to the granular nature of our samples as contrasted



FIG. 3. The Curie, Néel, and charge ordering temperatures for $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ samples under study. Open and solid symbols correspond to the samples with ¹⁶O and ¹⁸O, respectively. \otimes , \diamond , \boxtimes and \oplus , \triangle , \boxplus are the data from Refs. 15 and 22 for T_C , T_N , and T_{CO} .

with the single crystals studied in Ref. 27, or may be due to a formation of some weak superstructure of the CO type.¹⁴ As follows from the results of Ref. 27, the A-type AFM single crystals show metallike behavior in the ab plane, but are insulating in c direction. This can lead to an insulating behavior with small activation energy in our ceramic samples.

Another factor may be a possible instability of a metallic state. Most probably, the occupied orbitals in the *A*-type SmSr insulating phase for $x \ge 0.5$ are of $x^2 - y^2$ type,²⁴⁻²⁶ whereas these are ordered $3x^2 - r^2$ and $3y^2 - r^2$ in (LaPr)_{0.7}Ca_{0.3}MnO₃, the latter having the conventional charge ordering with the CE magnetic structure. The existence of a small energy gap in the *A*-type SmSr system may be related to the instability of a metallic state: the Hubbard subband of $x^2 - y^2$ type will have spectrum $\varepsilon(k) = -2t(\cos k_x + \cos k_y)$ and it will be half filled at x=0.5, which would give a nested Fermi surface. This can lead to a charge-density-wave state with the opening of a small gap. This should also give a superstructure with the wave vector $q = (\frac{1}{2}, \frac{1}{2}, 0)$ —the same as in the usual CO state, but with much weaker distortions. It would be interesting to look for such weak superstructure experimentally.

The present results show that the isotope substitution can drastically change the properties of the system when it is close to a FM-I crossover, independent of the detailed nature of the I phase. For the (LaPr)Ca system, this state is a "strong" insulator with the charge ordering and the CE magnetic ordering, whereas here, in SmSr system, it is a weak insulator of the *A*-type. Nevertheless, the effect of the isotope substitution is similar.

The detailed mechanism of the isotope effect on the properties of manganites is not yet completely clear, but most probably it is connected with the decrease in the electron bandwidth for heavier isotopes either due to zero-point oscillations or to polaronic effects.^{18,28} This is consistent with the change of T_{CO} and T_C with the isotope content, shown in Fig. 3. The short-range CO state is relatively insensitive to the isotope composition, which is quite natural if the mechanism of CO (or charge density wave) is predominantly electron-lattice interaction²⁹ (as is well known, the dimensionless electron-phonon coupling constant λ does not depend on the mass of ions). On the contrary, T_C in the double exchange model scales with the bandwidth, and the decrease in T_C with the growth of oxygen mass (Fig. 3) is consistent with this interpretation.

Summarizing, we studied the effect of the oxygen isotope substitution on the properties of $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ in the most interesting concentration range $0.4 \le x \le 0.6$. It was shown that close to a crossover from the ferromagnetic metallic state ($x \le 0.5$) to an antiferromagnetic insulator ($x \ge 0.5$), all the properties change drastically—up to the fact that for x = 0.475 and 0.5, one even induces the metal-insulator transition by the ${}^{16}\text{O} \rightarrow {}^{18}\text{O}$ substitution. Most probably this substitution transforms the FM state to an *A*-type antiferromagnetic

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net. We speculate that the relevant orbitals in this state are $x^2 - y^2$ ones and the energy gap appears due to the formation of a charge density wave in the $x^2 - y^2$ band. We conclude that this transition is induced by the decrease of the bandwidth for heavier ions. The results obtained, together with the earlier observed isotope-induced metal-insulator transition in $(La_{1-y}Pr_y)_{0.7}Ca_{0.3}MnO_3$, show that the isotope substitution is a powerful tool both for modifying the properties of manganites close to a crossover between different states and for the study of their physical characteristics.

We are grateful to A. N. Taldenkov and A. V. Inyushkin for helpful discussions and to A.I. Kurbakov for providing us with his neutron scattering data prior to publication. The work was supported by INTAS (Grant No. 01-2008), CRDF (Grant No. RP2-2355-MO-02), NWO (Grant No. 047-008-017), and RFBR (Grants Nos. 01-02-16240, 02-02-16708, 02-03-33258, and 00-15-96570).

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